

## Data Sheet

## ADG5206/ADG5207

### FEATURES

- Latch-up proof**
- 3.5 pF off source capacitance**
- Off drain capacitance**
  - ADG5206: 64 pF**
  - ADG5207: 33 pF**
- 0.35 pC typical charge injection**
- $\pm 0.01 \text{ nA}$  on channel leakage**
- Low on resistance: 155  $\Omega$  typical**
- $\pm 9 \text{ V}$  to  $\pm 22 \text{ V}$  dual-supply operation**
- 9 V to 40 V single-supply operation**
- $V_{SS}$  to  $V_{DD}$  analog signal range**
- Human body model (HBM) ESD rating**
  - 8 kV I/O port to supplies**
  - 2 kV I/O port to I/O port**
  - 8 kV all other pins**

### APPLICATIONS

- Automatic test equipment**
- Data acquisition**
- Instrumentation**
- Avionics**
- Battery monitoring**
- Communication systems**

### GENERAL DESCRIPTION

The **ADG5206** and **ADG5207** are monolithic CMOS analog multiplexers comprising 16 single channels and 8 differential channels, respectively. The **ADG5206** switches one of sixteen inputs to a common output, as determined by the 4-bit binary address lines, A0, A1, A2, and A3. The **ADG5207** switches one of eight differential inputs to a common differential output, as determined by the 3-bit binary address lines, A0, A1, and A2.

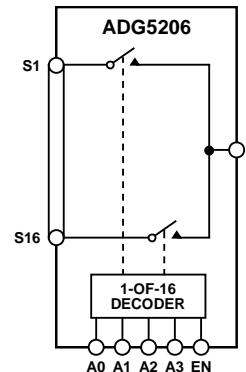
An EN input on both devices enables or disables the device. When EN is low, the device is disabled and all channels switch off. The ultralow capacitance and charge injection of these switches make them ideal solutions for data acquisition and sample-and-hold applications, where low glitch and fast settling are required. Fast switching speed coupled with high signal bandwidth make these devices suitable for video signal switching.

Each switch conducts equally well in both directions when on, and each switch has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked.

#### Rev. 0

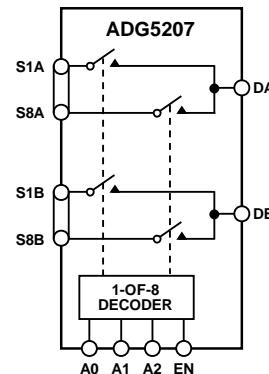
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

### FUNCTIONAL BLOCK DIAGRAMS



10714-001

Figure 1.



10714-002

Figure 2.

The **ADG5206/ADG5207** do not have  $V_L$  pins; instead, an on-chip voltage generator generates the logic power supply internally.

### PRODUCT HIGHLIGHTS

1. Trench Isolation Guards Against Latch-Up. A dielectric trench separates the P and N channel transistors to prevent latch-up even under severe overvoltage conditions.
2. Optimal switch design for low charge injection, low switch capacitance, and low leakage currents.
3. Dual-Supply Operation. For applications where the analog signal is bipolar, the **ADG5206/ADG5207** can be operated from dual supplies of up to  $\pm 22 \text{ V}$ .
4. Single-Supply Operation. For applications where the analog signal is unipolar, the **ADG5206/ADG5207** can be operated from a single rail power supply of up to 40 V.

## TABLE OF CONTENTS

Features .....	1	Absolute Maximum Ratings .....	10
Applications.....	1	ESD Caution.....	10
Functional Block Diagrams.....	1	Pin Configurations and Function Descriptions .....	11
General Description .....	1	Typical Performance Characteristics .....	15
Product Highlights .....	1	Test Circuits.....	20
Revision History .....	2	Terminology .....	22
Specifications.....	3	Applications Information .....	23
$\pm 15$ V Dual Supply .....	3	Trench Isolation.....	23
$\pm 20$ V Dual Supply .....	4	Outline Dimensions.....	24
12 V Single Supply.....	6	Ordering Guide .....	24
36 V Single Supply.....	8		
Continuous Current per Channel, Sx, D, or Dx.....	9		

## REVISION HISTORY

7/12—Revision 0: Initial Version

**SPECIFICATIONS** **$\pm 15$  V DUAL SUPPLY**

$V_{DD} = +15 \text{ V} \pm 10\%$ ,  $V_{SS} = -15 \text{ V} \pm 10\%$ , GND = 0 V, unless otherwise noted.

**Table 1.**

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH						
Analog Signal Range					V	
On Resistance, $R_{ON}$	155				$\Omega$ typ	$V_S = \pm 10 \text{ V}$ , $I_S = -1 \text{ mA}$ ; see Figure 30
On Resistance Match Between Channels, $\Delta R_{ON}$	200 4	225	250	285	$\Omega$ max $\Omega$ typ	$V_{DD} = +13.5 \text{ V}$ , $V_{SS} = -13.5 \text{ V}$ $V_S = \pm 10 \text{ V}$ , $I_S = -1 \text{ mA}$
On Resistance Flatness, $R_{FLAT(ON)}$	12 48 65	13	14	15	$\Omega$ max $\Omega$ typ $\Omega$ max	$V_S = \pm 10 \text{ V}$ , $I_S = -1 \text{ mA}$
LEAKAGE CURRENTS						
Source Off Leakage, $I_S$ (Off)	$\pm 0.005$				nA typ	$V_{DD} = +16.5 \text{ V}$ , $V_{SS} = -16.5 \text{ V}$
Match Between Channels, $\Delta$ Leakage, $I_S$ (Off) <sup>1</sup>	$\pm 0.1$ 0.01	$\pm 0.15$	$\pm 0.2$	$\pm 0.4$ 0.015	nA max nA typ	$V_S = \pm 10 \text{ V}$ , $V_D = \mp 10 \text{ V}$
Drain Off Leakage, $I_D$ (Off)						$V_S = \pm 10 \text{ V}$ , $V_D = \mp 10 \text{ V}$ ; see Figure 31
ADG5206	$\pm 0.02$				nA typ	
ADG5207	$\pm 0.1$ $\pm 0.02$	$\pm 0.25$	$\pm 0.6$	$\pm 3.3$	nA max nA typ	
Match Between Channels, $\Delta$ Leakage, $I_D$ (Off), ADG5207 Only	0.015	$\pm 0.25$	$\pm 0.4$	$\pm 1.7$ 0.015	nA max nA typ	$V_S = \pm 10 \text{ V}$ , $V_D = \mp 10 \text{ V}$
Channel On Leakage, $I_D$ (On), $I_S$ (On)						$V_S = V_D = \pm 10 \text{ V}$ ; see Figure 32
ADG5206	$\pm 0.02$				nA typ	
ADG5207	$\pm 0.1$ $\pm 0.02$	$\pm 0.25$	$\pm 0.6$	$\pm 3.3$	nA max nA typ	
Match Between Channels, $\Delta$ Leakage, $I_D$ (On), $I_S$ (On) <sup>2</sup>	0.01	$\pm 0.2$	$\pm 0.4$	$\pm 1.7$ 0.03	nA max nA typ	$V_S = V_D = \pm 10 \text{ V}$
DIGITAL INPUTS						
Input High Voltage, $V_{INH}$				2.0	V min	
Input Low Voltage, $V_{INL}$				0.8	V max	
Input Current, $I_{INL}$ or $I_{INH}$	0.002			$\pm 0.1$	$\mu\text{A}$ typ $\mu\text{A}$ max	$V_{IN} = V_{GND}$ or $V_{DD}$
Digital Input Capacitance, $C_{IN}$	3				pF typ	
DYNAMIC CHARACTERISTICS <sup>3</sup>						
Transition Time, $t_{TRANSITION}$	200				ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
$t_{ON}$ (EN)	260 180	300	320	360	ns max ns typ	$V_S = 10 \text{ V}$ ; see Figure 33 $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
$t_{OFF}$ (EN)	245 140	260	270	285	ns max ns typ	$V_S = 10 \text{ V}$ ; see Figure 34 $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
Break-Before-Make Time Delay, $t_D$	200 85	220	240	270 27	ns max ns typ ns min	$V_S = 10 \text{ V}$ ; see Figure 34 $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$ $V_{S1} = V_{S2} = 10 \text{ V}$ ; see Figure 35

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
Charge Injection, Q <sub>INJ</sub>	0.35				pC typ	V <sub>S</sub> = 0 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF; see Figure 36
Off Isolation	±1.8			±2	pC typ	V <sub>S</sub> = ±10 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF
	-90				dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 37
Channel-to-Channel Crosstalk	-76				dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 38
-3 dB Bandwidth						R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF; see Figure 39
ADG5206	60				MHz typ	
ADG5207	140				MHz typ	
Insertion Loss	6.4				dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 39
C <sub>S</sub> (Off)	3.5				pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
C <sub>D</sub> (Off)						
ADG5206	64				pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
ADG5207	33				pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
C <sub>D</sub> (On), C <sub>S</sub> (On)						
ADG5206	68				pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
ADG5207	36				pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
POWER REQUIREMENTS						
I <sub>DD</sub>	45				μA typ	V <sub>DD</sub> = +16.5 V, V <sub>SS</sub> = -16.5 V
	55			70	μA max	Digital inputs = 0 V or V <sub>DD</sub>
I <sub>SS</sub>	0.001				μA typ	
				1	μA max	Digital inputs = 0 V or V <sub>DD</sub>
V <sub>DD</sub> /V <sub>SS</sub>				±9/±22	V min/V max	GND = 0 V

<sup>1</sup>The off channel leakage delta is calculated using the maximum of V<sub>S</sub> = +10 V and V<sub>D</sub> = -10 V, or V<sub>S</sub> = -10 V and V<sub>D</sub> = +10 V.

<sup>2</sup>The on channel leakage delta is calculated using the maximum of V<sub>S</sub> = V<sub>D</sub> = +10 V, or V<sub>S</sub> = V<sub>D</sub> = -10 V.

<sup>3</sup>Guaranteed by design; not subject to production test.

## ±20 V DUAL SUPPLY

V<sub>DD</sub> = +20 V ± 10%, V<sub>SS</sub> = -20 V ± 10%, GND = 0 V, unless otherwise noted.

Table 2.

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH						
Analog Signal Range				V <sub>DD</sub> to V <sub>SS</sub>	V	
On Resistance, R <sub>ON</sub>	130				Ω typ	V <sub>S</sub> = ±15 V, I <sub>S</sub> = -1 mA; see Figure 30
	160	180	200	230	Ω max	V <sub>DD</sub> = +18 V, V <sub>SS</sub> = -18 V
On-Resistance Match Between Channels, ΔR <sub>ON</sub>	4				Ω typ	V <sub>S</sub> = ±15 V, I <sub>S</sub> = -1 mA
	12	13	14	15	Ω max	
On-Resistance Flatness, R <sub>FLAT(ON)</sub>	35				Ω typ	V <sub>S</sub> = ±15 V, I <sub>S</sub> = -1 mA
	50	58	65	75	Ω max	

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
LEAKAGE CURRENTS						
Source Off Leakage, $I_s$ (Off)	$\pm 0.005$				nA typ	$V_{DD} = +22\text{ V}$ , $V_{SS} = -22\text{ V}$
Match Between Channels, $\Delta$ Leakage, $I_s$ (Off) <sup>1</sup>	$\pm 0.1$ 0.01	$\pm 0.15$	$\pm 0.2$	$\pm 0.4$ 0.015	nA max nA typ	$V_s = \pm 15\text{ V}$ , $V_D = \mp 15\text{ V}$ ; see Figure 31
Drain Off Leakage, $I_D$ (Off)						$V_s = \pm 15\text{ V}$ , $V_D = \mp 15\text{ V}$ ; see Figure 31
ADG5206	$\pm 0.02$				nA typ	
ADG5207	$\pm 0.1$ $\pm 0.02$	$\pm 0.25$	$\pm 0.6$	$\pm 3.3$	nA max nA typ	
Match Between Channels, $\Delta$ Leakage, $I_D$ (Off), ADG5207 Only	$\pm 0.1$ 0.015	$\pm 0.25$	$\pm 0.4$	$\pm 1.7$ 0.015	nA max nA typ	
Channel On Leakage, $I_D$ (On), $I_s$ (On)						$V_s = V_D = \pm 15\text{ V}$ ; see Figure 32
ADG5206	$\pm 0.02$				nA typ	
ADG5207	$\pm 0.1$ $\pm 0.02$	$\pm 0.25$	$\pm 0.6$	$\pm 3.3$	nA max nA typ	
Match Between Channels, $\Delta$ Leakage, $I_D$ (On), $I_s$ (On) <sup>2</sup>	$\pm 0.1$ 0.01	$\pm 0.2$	$\pm 0.4$	$\pm 1.7$ 0.03	nA max nA typ	
DIGITAL INPUTS						
Input High Voltage, $V_{INH}$				2.0	V min	
Input Low Voltage, $V_{INL}$				0.8	V max	
Input Current, $I_{INL}$ or $I_{INH}$	$\pm 0.002$			$\pm 0.1$	$\mu\text{A}$ typ $\mu\text{A}$ max	$V_{IN} = V_{GND}$ or $V_{DD}$
Digital Input Capacitance, $C_{IN}$	3				pF typ	
DYNAMIC CHARACTERISTICS <sup>3</sup>						
Transition Time, $t_{TRANSITION}$	185				ns typ	$R_L = 300\Omega$ , $C_L = 35\text{ pF}$
	240	270	290	320	ns max	$V_s = 10\text{ V}$ ; see Figure 33
$t_{ON}$ (EN)	175				ns typ	$R_L = 300\Omega$ , $C_L = 35\text{ pF}$
	230	245	255	270	ns max	$V_s = 10\text{ V}$ ; see Figure 34
$t_{OFF}$ (EN)	135				ns typ	$R_L = 300\Omega$ , $C_L = 35\text{ pF}$
	185	205	220	245	ns max	$V_s = 10\text{ V}$ ; see Figure 34
Break-Before-Make Time Delay, $t_D$	75			27	ns min	$R_L = 300\Omega$ , $C_L = 35\text{ pF}$
					pC typ	$V_{S1} = V_{S2} = 10\text{ V}$ ; see Figure 35
Charge Injection, $Q_{INJ}$	0.45					$V_s = 0\text{ V}$ , $R_s = 0\Omega$ , $C_L = 1\text{ nF}$ ; see Figure 36
	$\pm 4$			$\pm 4$	pC typ	$V_s = \pm 10\text{ V}$ , $R_s = 0\Omega$ , $C_L = 1\text{ nF}$
Off Isolation	-90				dB typ	$R_L = 50\Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 37
Channel-to-Channel Crosstalk	-76				dB typ	$R_L = 50\Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 38
-3 dB Bandwidth						$R_L = 50\Omega$ , $C_L = 5\text{ pF}$ ; see Figure 39
ADG5206	65				MHz typ	
ADG5207	145				MHz typ	
Insertion Loss	5.6				dB typ	$R_L = 50\Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 39
$C_s$ (Off)	3.3				pF typ	$V_s = 0\text{ V}$ , $f = 1\text{ MHz}$

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
C <sub>D</sub> (Off) <a href="#">ADG5206</a> <a href="#">ADG5207</a>	62 32				pF typ pF typ	V <sub>S</sub> = 0 V, f = 1 MHz V <sub>S</sub> = 0 V, f = 1 MHz
C <sub>D</sub> (On), C <sub>S</sub> (On) <a href="#">ADG5206</a> <a href="#">ADG5207</a>	67 35				pF typ pF typ	V <sub>S</sub> = 0 V, f = 1 MHz V <sub>S</sub> = 0 V, f = 1 MHz
POWER REQUIREMENTS						
I <sub>DD</sub>	50 70		110		μA typ μA max	V <sub>DD</sub> = +22 V, V <sub>SS</sub> = -22 V Digital inputs = 0 V or V <sub>DD</sub>
I <sub>SS</sub>	0.001		1		μA typ μA max	Digital inputs = 0 V or V <sub>DD</sub>
V <sub>DD</sub> /V <sub>SS</sub>			±9/±22		V min/V max	GND = 0 V

<sup>1</sup>The off channel leakage delta is calculated using the maximum of V<sub>S</sub> = +15 V and V<sub>D</sub> = -15 V, or V<sub>S</sub> = -15 V and V<sub>D</sub> = +15 V.

<sup>2</sup>The on channel leakage delta is calculated using the maximum of V<sub>S</sub> = V<sub>D</sub> = +15 V, or V<sub>S</sub> = V<sub>D</sub> = -15 V.

<sup>3</sup>Guaranteed by design; not subject to production test.

## 12 V SINGLE SUPPLY

V<sub>DD</sub> = 12 V ± 10%, V<sub>SS</sub> = 0 V, GND = 0 V, unless otherwise noted.

Table 3.

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH						
Analog Signal Range			0 V to V <sub>DD</sub>		V	
On Resistance, R <sub>ON</sub>	350				Ω typ	V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = -1 mA; see Figure 30
On-Resistance Match Between Channels, ΔR <sub>ON</sub>	500 5	560 610	610 700		Ω max Ω typ	V <sub>DD</sub> = 10.8 V, V <sub>SS</sub> = 0 V V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = -1 mA
On-Resistance Flatness, R <sub>FLAT (ON)</sub>	20 170 280	21 310	22 335	24 370	Ω max Ω typ Ω max	V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = -1 mA
LEAKAGE CURRENTS						
Source Off Leakage, I <sub>S</sub> (Off)	±0.005				nA typ	V <sub>DD</sub> = +13.2 V, V <sub>SS</sub> = 0 V V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 10 V/1 V; see Figure 31
Match Between Channels, ΔLeakage, I <sub>S</sub> (Off) <sup>1</sup>	±0.1 0.01	±0.15	±0.2	±0.4 0.015	nA max nA typ	
Drain Off Leakage, I <sub>D</sub> (Off)						V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 1 V/10 V; see Figure 31
ADG5206	±0.02				nA typ	
ADG5207	±0.1 ±0.02 ±0.1 0.015	±0.25	±0.6	±3.3 0.015	nA max nA typ nA max nA typ	
Match Between Channels, ΔLeakage, I <sub>D</sub> (Off), ADG5207 Only	±0.02				nA typ	
Channel On Leakage, I <sub>D</sub> (On), I <sub>S</sub> (On)	±0.02 ±0.1 ±0.02 ±0.1 0.01	±0.25	±0.6	±3.3 0.015 ±1.7 0.015 0.03	nA typ nA max nA typ nA max nA typ	V <sub>S</sub> = V <sub>D</sub> = 1 V/10 V; see Figure 32
ADG5206	±0.02				nA typ	
ADG5207	±0.1 ±0.02 ±0.1 0.01	±0.25	±0.4	±3.3 ±1.7 ±1.7 0.03	nA max nA typ nA max nA typ	
Match Between Channels, ΔLeakage, I <sub>D</sub> (On), I <sub>S</sub> (On) <sup>2</sup>	±0.02				nA typ	

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
DIGITAL INPUTS						
Input High Voltage, $V_{INH}$				2.0	V min	
Input Low Voltage, $V_{INL}$				0.8	V max	
Input Current, $I_{INL}$ or $I_{INH}$	0.002			±0.1	μA typ	$V_{IN} = V_{GND}$ or $V_{DD}$
Digital Input Capacitance, $C_{IN}$	3				pF typ	
DYNAMIC CHARACTERISTICS <sup>3</sup>						
Transition Time, $t_{TRANSITION}$	290				ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
	290	440	480	550	ns max	$V_S = 8 \text{ V}$ ; see Figure 33
$t_{ON}$ (EN)	230				ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
	290	320	340	370	ns max	$V_S = 8 \text{ V}$ ; see Figure 34
$t_{OFF}$ (EN)	230				ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
	315	360	390	450	ns max	$V_S = 8 \text{ V}$ ; see Figure 34
Break-Before-Make Time Delay, $t_D$	170			45	ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
					ns min	$V_{S1} = V_{S2} = 8 \text{ V}$ ; see Figure 35
Charge Injection, $Q_{INJ}$	0.25				pC typ	$V_S = 6 \text{ V}$ , $R_S = 0 \Omega$ , $C_L = 1 \text{ nF}$ ; see Figure 36
	±0.6			±0.7	pC typ	$V_S = 0 \text{ V}$ to $10 \text{ V}$ , $R_S = 0 \Omega$ , $C_L = 1 \text{nF}$
Off Isolation	−90				dB typ	$R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ , $f = 1 \text{ MHz}$ ; see Figure 37
Channel-to-Channel Crosstalk	−76				dB typ	$R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ , $f = 1 \text{ MHz}$ ; see Figure 38
−3 dB Bandwidth					MHz typ	$R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ ; see Figure 39
ADG5206	50				MHz typ	
ADG5207	105				MHz typ	
Insertion Loss	8.55				dB typ	$R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ , $f = 1 \text{ MHz}$ ; see Figure 39
$C_S$ (Off)	3.6				pF typ	$V_S = 6 \text{ V}$ , $f = 1 \text{ MHz}$
$C_D$ (Off)						
ADG5206	71				pF typ	$V_S = 6 \text{ V}$ , $f = 1 \text{ MHz}$
ADG5207	36				pF typ	$V_S = 6 \text{ V}$ , $f = 1 \text{ MHz}$
$C_D$ (On), $C_S$ (On)						
ADG5206	75				pF typ	$V_S = 6 \text{ V}$ , $f = 1 \text{ MHz}$
ADG5207	40				pF typ	$V_S = 6 \text{ V}$ , $f = 1 \text{ MHz}$
POWER REQUIREMENTS						
$I_{DD}$	40				μA typ	$V_{DD} = 13.2 \text{ V}$
	50		65	9/40	μA max	Digital inputs = 0 V or $V_{DD}$
$V_{DD}$					V min/V max	GND = 0 V, $V_{SS} = 0 \text{ V}$

<sup>1</sup> The off channel leakage delta is calculated using the maximum of  $V_S = 1 \text{ V}$  and  $V_D = 10 \text{ V}$ , or  $V_S = 10 \text{ V}$  and  $V_D = 1 \text{ V}$ .

<sup>2</sup> The on channel leakage delta is calculated using the maximum of  $V_S = V_D = 1 \text{ V}$ , or  $V_S = V_D = 10 \text{ V}$ .

<sup>3</sup> Guaranteed by design; not subject to production test.

**36 V SINGLE SUPPLY**

$V_{DD} = 36 \text{ V} \pm 10\%$ ,  $V_{SS} = 0 \text{ V}$ , GND = 0 V, unless otherwise noted.

**Table 4.**

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
<b>ANALOG SWITCH</b>						
Analog Signal Range				0 V to $V_{DD}$	V	
On Resistance, $R_{ON}$	140				$\Omega$ typ	$V_S = 0 \text{ V}$ to 30 V, $I_S = -1 \text{ mA}$ ; see Figure 30
On-Resistance Match Between Channels, $\Delta R_{ON}$	170 4	195	215	245	$\Omega$ max $\Omega$ typ	$V_{DD} = 32.4 \text{ V}$ , $V_{SS} = 0 \text{ V}$
On-Resistance Flatness, $R_{FLAT(ON)}$	12 40 55	13	14	15	$\Omega$ max $\Omega$ typ $\Omega$ max	$V_S = 0 \text{ V}$ to 30 V, $I_S = -1 \text{ mA}$
LEAKAGE CURRENTS						
Source Off Leakage, $I_S$ (Off)	$\pm 0.005$				nA typ	$V_{DD} = 39.6 \text{ V}$ , $V_{SS} = 0 \text{ V}$
Match Between Channels, $\Delta I_S$ (Off) <sup>1</sup>	$\pm 0.1$ 0.01	$\pm 0.15$	$\pm 0.2$	$\pm 0.4$ 0.015	nA max nA typ	$V_S = 1 \text{ V}/30 \text{ V}$ , $V_D = 30 \text{ V}/1 \text{ V}$ ; see Figure 31
Drain Off Leakage, $I_D$ (Off)						$V_S = 1 \text{ V}/30 \text{ V}$ , $V_D = 30 \text{ V}/1 \text{ V}$ ; see Figure 31
ADG5206	$\pm 0.02$				nA typ	
ADG5207	$\pm 0.1$ $\pm 0.02$	$\pm 0.25$	$\pm 0.6$	$\pm 3.3$	nA max nA typ	
Match Between Channels, $\Delta I_D$ (Off), ADG5207 Only	$\pm 0.1$ 0.015	$\pm 0.25$	$\pm 0.4$	$\pm 1.7$ 0.015	nA max nA typ	
Channel On Leakage, $I_D$ (On), $I_S$ (On)						$V_S = V_D = 1 \text{ V}/30 \text{ V}$ ; see Figure 32
ADG5206	$\pm 0.02$				nA typ	
ADG5207	$\pm 0.1$ $\pm 0.02$	$\pm 0.25$	$\pm 0.6$	$\pm 3.3$	nA max nA typ	
Match Between Channels, $\Delta I_D$ (On), $I_S$ (On) <sup>2</sup>	$\pm 0.1$ 0.01	$\pm 0.2$	$\pm 0.4$	$\pm 1.7$ 0.03	nA max nA typ	
<b>DIGITAL INPUTS</b>						
Input High Voltage, $V_{INH}$			2.0		V min	
Input Low Voltage, $V_{INL}$			0.8		V max	
Input Current, $I_{INL}$ or $I_{INH}$	0.002			$\pm 0.1$	$\mu\text{A}$ typ $\mu\text{A}$ max	$V_{IN} = V_{GND}$ or $V_{DD}$
Digital Input Capacitance, $C_{IN}$	3				pF typ	
<b>DYNAMIC CHARACTERISTICS<sup>3</sup></b>						
Transition Time, $t_{TRANSITION}$	225				ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
$t_{ON}$ (EN)	290 215	310	320	350	ns max ns typ	$V_S = 18 \text{ V}$ ; see Figure 33
$t_{OFF}$ (EN)	265 170	285	285	295	ns max ns typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
Break-Before-Make Time Delay, $t_D$	215 90	230	245	270	ns max ns typ	$V_S = 18 \text{ V}$ ; see Figure 34
Charge Injection, $Q_{INJ}$	0.7 $\pm 3$			28 $\pm 3$	$\text{pC}$ typ $\text{pC}$ typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$
						$V_{S1} = V_{S2} = 18 \text{ V}$ ; see Figure 35
						$V_S = 18 \text{ V}$ , $R_S = 0 \Omega$ , $C_L = 1 \text{ nF}$ ; see Figure 36
						$V_S = 0 \text{ V}$ to 30 V, $R_S = 0 \Omega$ , $C_L = 1 \text{ nF}$

Parameter	25°C	-40°C to +60°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
Off Isolation	-90				dB typ	$R_L = 50 \Omega, C_L = 5 \text{ pF}, f = 1 \text{ MHz}$ ; see Figure 37
Channel-to-Channel Crosstalk	-76				dB typ	$R_L = 50 \Omega, C_L = 5 \text{ pF}, f = 1 \text{ MHz}$ ; see Figure 38
-3 dB Bandwidth						$R_L = 50 \Omega, C_L = 5 \text{ pF}$ ; see Figure 39
ADG5206	55				MHz typ	
ADG5207	115				MHz typ	
Insertion Loss	5.65				dB typ	$R_L = 50 \Omega, C_L = 5 \text{ pF}, f = 1 \text{ MHz}$ ; see Figure 39
$C_S$ (Off)	3.4				pF typ	$V_S = 18 \text{ V}, f = 1 \text{ MHz}$
$C_D$ (Off)						
ADG5206	62				pF typ	$V_S = 18 \text{ V}, f = 1 \text{ MHz}$
ADG5207	32				pF typ	$V_S = 18 \text{ V}, f = 1 \text{ MHz}$
$C_D$ (On), $C_S$ (On)						
ADG5206	66				pF typ	$V_S = 18 \text{ V}, f = 1 \text{ MHz}$
ADG5207	35				pF typ	$V_S = 18 \text{ V}, f = 1 \text{ MHz}$
POWER REQUIREMENTS						
$I_{DD}$	80				μA typ	$V_{DD} = 39.6 \text{ V}$
	100		130		μA max	Digital inputs = 0 V or $V_{DD}$
$V_{DD}$			9/40		V min/V max	GND = 0 V, $V_{SS} = 0 \text{ V}$

<sup>1</sup> The off channel leakage delta is calculated using the maximum of  $V_S = 1 \text{ V}$  and  $V_D = 30 \text{ V}$ , or  $V_S = 30 \text{ V}$  and  $V_D = 1 \text{ V}$ .

<sup>2</sup> The on channel leakage delta is calculated using the maximum of  $V_S = V_D = 1 \text{ V}$ , or  $V_S = V_D = 30 \text{ V}$ .

<sup>3</sup> Guaranteed by design; not subject to production test.

## CONTINUOUS CURRENT PER CHANNEL, Sx, D, OR Dx

Table 5. ADG5206

Parameter	25°C	60°C	85°C	125°C	Unit
CONTINUOUS CURRENT, Sx OR D					
$V_{DD} = +15 \text{ V}, V_{SS} = -15 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	44	32	23	12	mA maximum
$V_{DD} = +20 \text{ V}, V_{SS} = -20 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	47	33	24	12	mA maximum
$V_{DD} = 12 \text{ V}, V_{SS} = 0 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	31	24	19	11	mA maximum
$V_{DD} = 36 \text{ V}, V_{SS} = 0 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	46	33	24	12	mA maximum

Table 6. ADG5207

Parameter	25°C	60°C	85°C	125°C	Unit
CONTINUOUS CURRENT, Sx OR Dx					
$V_{DD} = +15 \text{ V}, V_{SS} = -15 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	33	25	19	11	mA maximum
$V_{DD} = +20 \text{ V}, V_{SS} = -20 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	35	27	20	11	mA maximum
$V_{DD} = 12 \text{ V}, V_{SS} = 0 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	23	19	15	10	mA maximum
$V_{DD} = 36 \text{ V}, V_{SS} = 0 \text{ V}$ TSSOP ( $\theta_{JA} = 67.7^\circ\text{C}/\text{W}$ )	34	26	20	11	mA maximum

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 7.

Parameter	Rating
$V_{DD}$ to $V_{SS}$	48 V
$V_{DD}$ to GND	-0.3 V to +48 V
$V_{SS}$ to GND	+0.3 V to -48 V
Analog Inputs <sup>1</sup>	$V_{SS} - 0.3 \text{ V}$ to $V_{DD} + 0.3 \text{ V}$ or 30 mA, whichever occurs first
Digital Inputs <sup>1</sup>	$V_{SS} - 0.3 \text{ V}$ to $V_{DD} + 0.3 \text{ V}$ or 30 mA, whichever occurs first
Peak Current, Sx, D, or Dx Pins  ADG5206	140 mA (pulsed at 1 ms, 10% duty cycle maximum)
ADG5207	105 mA (pulsed at 1 ms, 10% duty cycle maximum)
Continuous Current, Sx, D, or Dx Pins <sup>2</sup>	Data + 15%
Temperature Range	
Operating	-40°C to +125°C
Storage	-65°C to +150°C
Junction Temperature	150°C
Thermal Impedance, $\theta_{JA}$	
32-Lead TSSOP (4-Layer Board)	67.7°C/W
Reflow Soldering Peak Temperature, Pb Free	260(+0/-5)°C
HBM ESD	
I/O Port to Supplies	8 kV
I/O Port to I/O Port	2 kV
All Other Pins	8 kV

<sup>1</sup> Overvoltages at the Ax, EN, Sx, D, and Dx pins are clamped by internal diodes. Limit current to the maximum ratings given.

<sup>2</sup> See Table 5 and Table 6.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating can be applied at any one time.

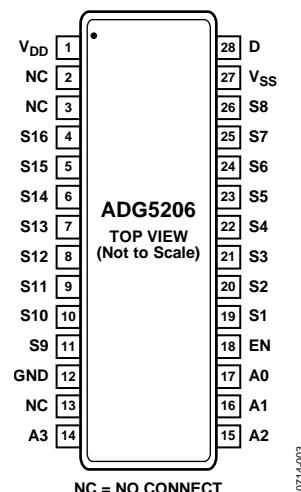
### ESD CAUTION



#### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



10714-003

Figure 3. ADG5206 Pin Configuration

Table 8. ADG5206 Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V <sub>DD</sub>	Most Positive Power Supply Potential.
2, 3, 13	NC	No Connect. Not internally connected.
4	S16	Source Terminal 16. This pin can be an input or an output.
5	S15	Source Terminal 15. This pin can be an input or an output.
6	S14	Source Terminal 14. This pin can be an input or an output.
7	S13	Source Terminal 13. This pin can be an input or an output.
8	S12	Source Terminal 12. This pin can be an input or an output.
9	S11	Source Terminal 11. This pin can be an input or an output.
10	S10	Source Terminal 10. This pin can be an input or an output.
11	S9	Source Terminal 9. This pin can be an input or an output.
12	GND	Ground (0 V) Reference.
14	A3	Logic Control Input.
15	A2	Logic Control Input.
16	A1	Logic Control Input.
17	A0	Logic Control Input.
18	EN	Active High Digital Input. When this pin is low, the device is disabled and all switches are turned off. When this pin is high, the Ax logic inputs determine which switch is turned on.
19	S1	Source Terminal 1. This pin can be an input or an output.
20	S2	Source Terminal 2. This pin can be an input or an output.
21	S3	Source Terminal 3. This pin can be an input or an output.
22	S4	Source Terminal 4. This pin can be an input or an output.
23	S5	Source Terminal 5. This pin can be an input or an output.
24	S6	Source Terminal 6. This pin can be an input or an output.
25	S7	Source Terminal 7. This pin can be an input or an output.
26	S8	Source Terminal 8. This pin can be an input or an output.
27	V <sub>SS</sub>	Most Negative Power Supply Potential. In single-supply applications, this pin can be connected to ground.
28	D	Drain Terminal. This pin can be an input or an output.

Table 9. ADG5206 Truth Table

A3	A2	A1	A0	EN	On Switch
X	X	X	X	0	None
0	0	0	0	1	1
0	0	0	1	1	2
0	0	1	0	1	3
0	0	1	1	1	4
0	1	0	0	1	5
0	1	0	1	1	6
0	1	1	0	1	7
0	1	1	1	1	8
1	0	0	0	1	9
1	0	0	1	1	10
1	0	1	0	1	11
1	0	1	1	1	12
1	1	0	0	1	13
1	1	0	1	1	14
1	1	1	0	1	15
1	1	1	1	1	16

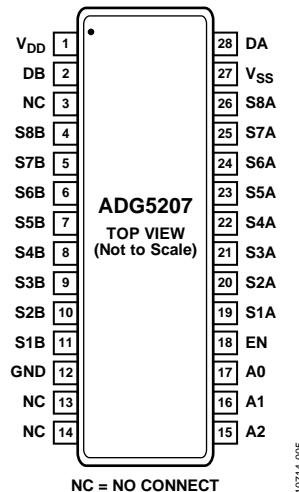


Figure 4. ADG5207 Pin Configuration

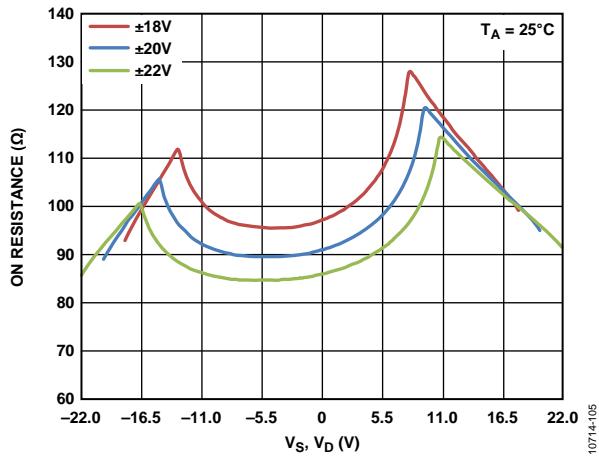
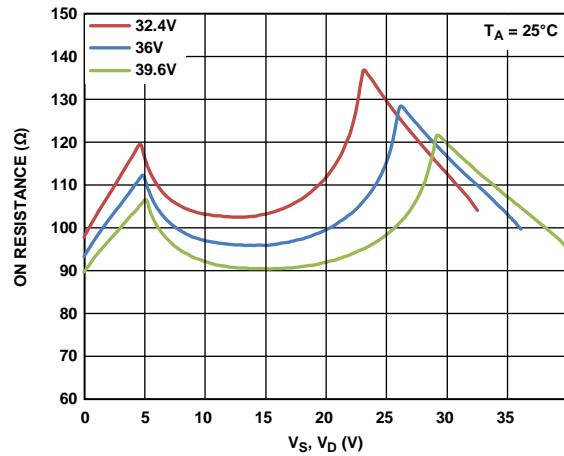
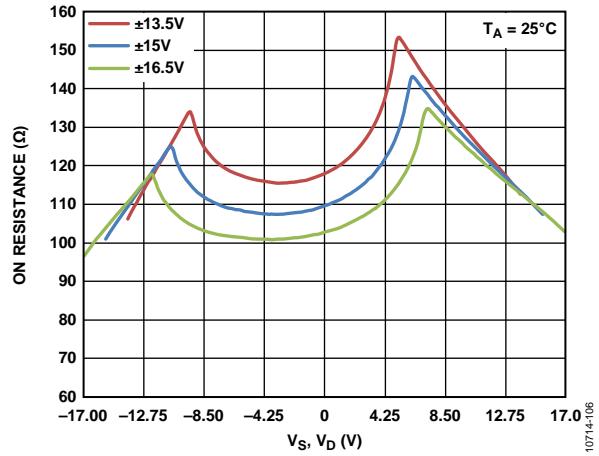
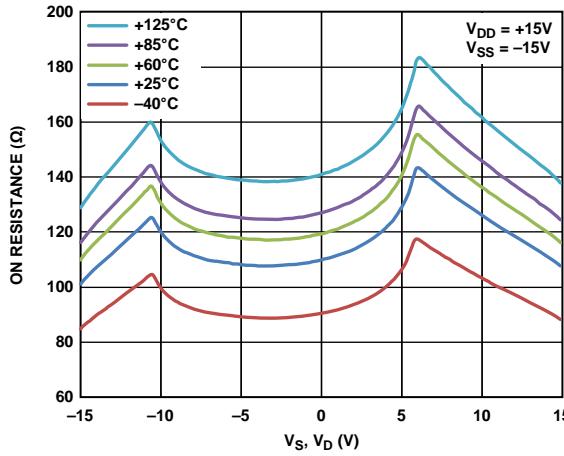
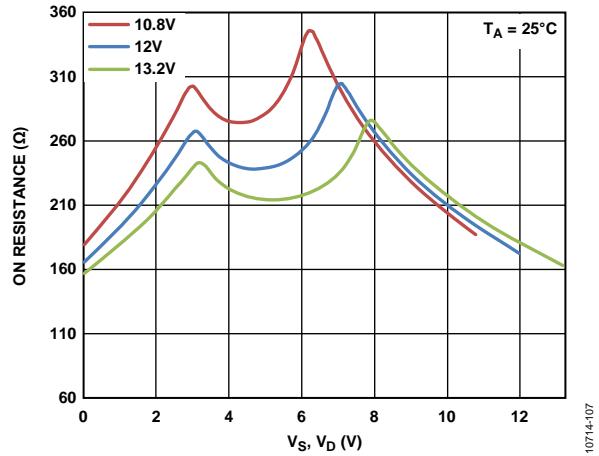
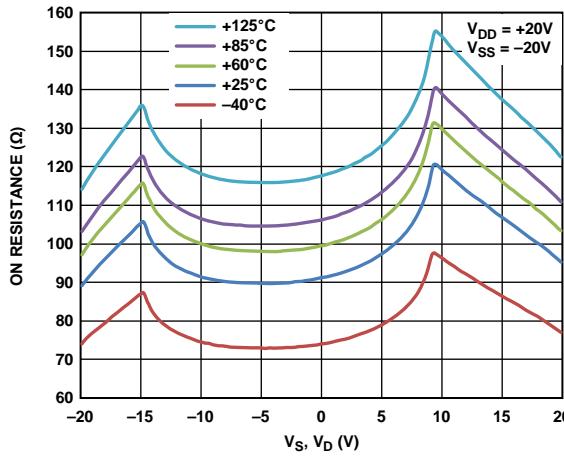
Table 10. ADG5207 Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V <sub>DD</sub>	Most Positive Power Supply Potential.
2	DB	Drain Terminal B. This pin can be an input or an output.
3, 13, 14	NC	No Connect. Not internally connected.
4	S8B	Source Terminal 8B. This pin can be an input or an output.
5	S7B	Source Terminal 7B. This pin can be an input or an output.
6	S6B	Source Terminal 6B. This pin can be an input or an output.
7	S5B	Source Terminal 5B. This pin can be an input or an output.
8	S4B	Source Terminal 4B. This pin can be an input or an output.
9	S3B	Source Terminal 3B. This pin can be an input or an output.
10	S2B	Source Terminal 2B. This pin can be an input or an output.
11	S1B	Source Terminal 1B. This pin can be an input or an output.
12	GND	Ground (0 V) Reference.
15	A2	Logic Control Input.
16	A1	Logic Control Input.
17	A0	Logic Control Input.
18	EN	Active High Digital Input. When this pin is low, the device is disabled and all switches are turned off. When this pin is high, the Ax logic inputs determine which switch is turned on.
19	S1A	Source Terminal 1A. This pin can be an input or an output.
20	S2A	Source Terminal 2A. This pin can be an input or an output.
21	S3A	Source Terminal 3A. This pin can be an input or an output.
22	S4A	Source Terminal 4A. This pin can be an input or an output.
23	S5A	Source Terminal 5A. This pin can be an input or an output.
24	S6A	Source Terminal 6A. This pin can be an input or an output.
25	S7A	Source Terminal 7A. This pin can be an input or an output.
26	S8A	Source Terminal 8A. This pin can be an input or an output.
27	V <sub>SS</sub>	Most Negative Power Supply Potential. In single-supply applications, this pin can be connected to ground.
28	DA	Drain Terminal A. This pin can be an input or an output.

Table 11. ADG5207 Truth Table

A2	A1	A0	EN	On Switch Pair
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

## TYPICAL PERFORMANCE CHARACTERISTICS

Figure 5.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  ( $\pm 20\text{V}$  Dual Supply)Figure 8.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  (36V Single Supply)Figure 6.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  ( $\pm 15\text{V}$  Dual Supply)Figure 9.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  for Different Temperatures,  $\pm 15\text{V}$  Dual SupplyFigure 7.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  (12V Single Supply)Figure 10.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  for Different Temperatures,  $\pm 20\text{V}$  Dual Supply

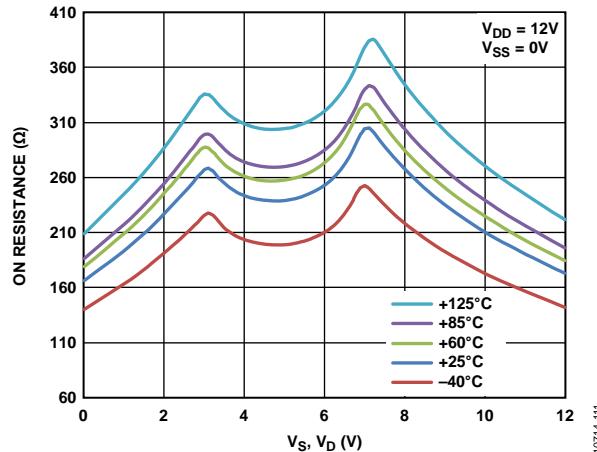


Figure 11.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  for Different Temperatures,  
12 V Single Supply

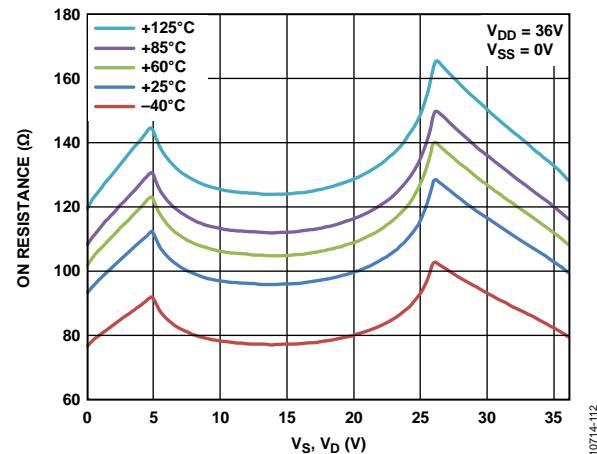


Figure 12.  $R_{ON}$  as a Function of  $V_S$ ,  $V_D$  for Different Temperatures,  
36 V Single Supply

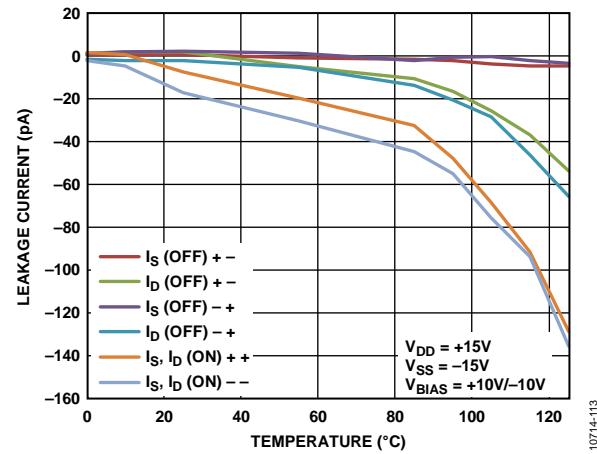


Figure 13. Leakage Currents vs. Temperature, ±15 V Dual Supply

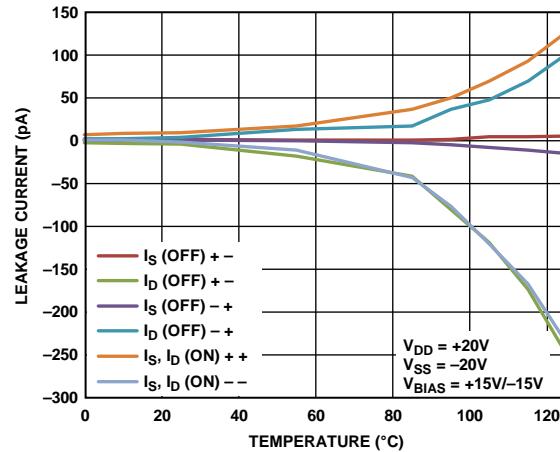


Figure 14. Leakage Currents vs. Temperature, ±20 V Dual Supply

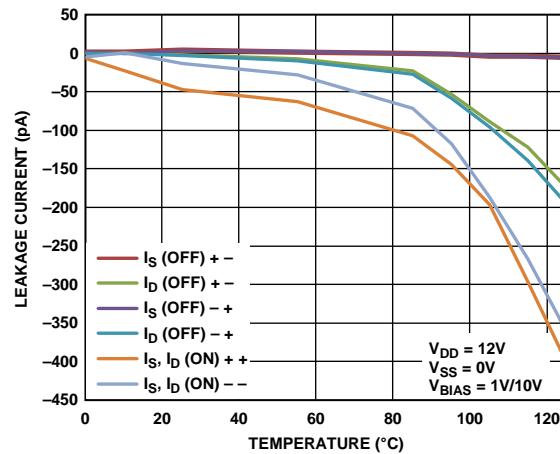


Figure 15. Leakage Currents vs. Temperature, 12 V Single Supply

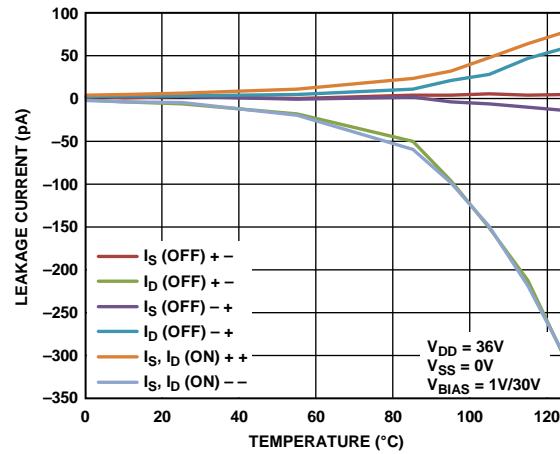


Figure 16. Leakage Currents vs. Temperature, 36 V Single Supply

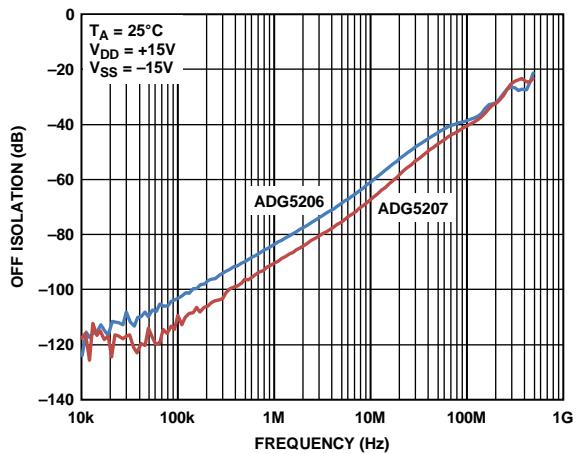
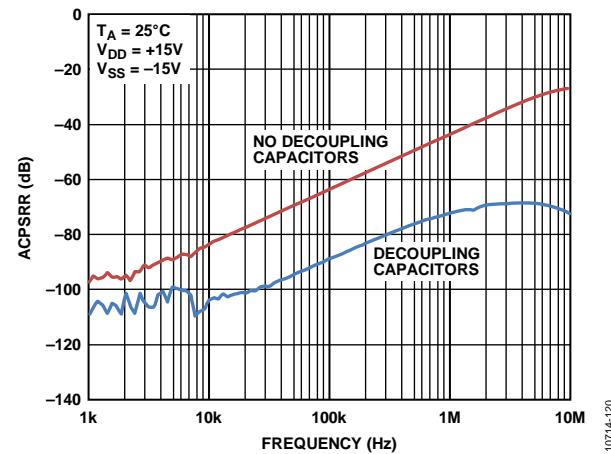
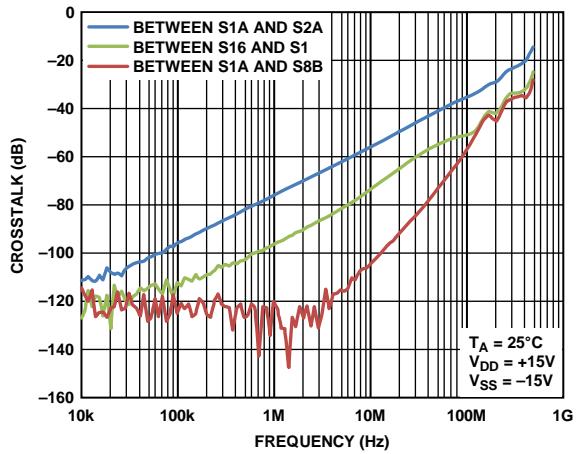
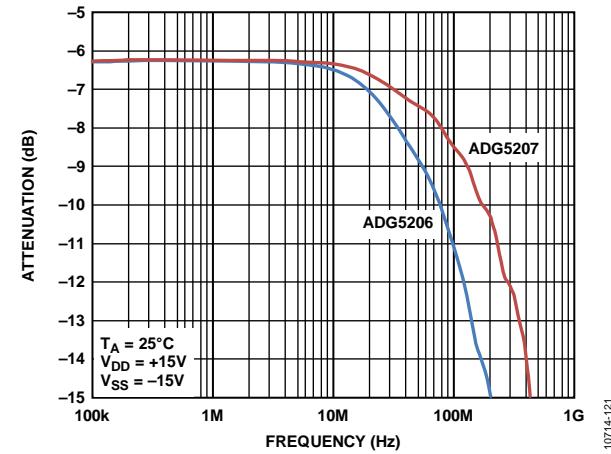
Figure 17. Off Isolation vs. Frequency,  $\pm 15\text{ V}$  Dual SupplyFigure 20. ACPSRR vs. Frequency,  $\pm 15\text{ V}$  Dual SupplyFigure 18. Crosstalk vs. Frequency,  $\pm 15\text{ V}$  Dual Supply

Figure 21. Bandwidth

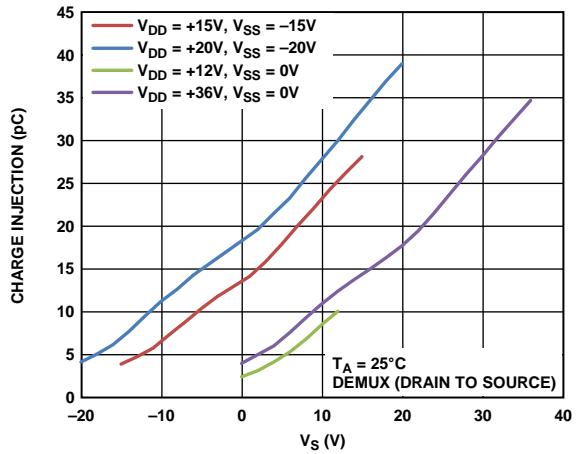


Figure 19. Charge Injection vs. Source Voltage, Drain to Source

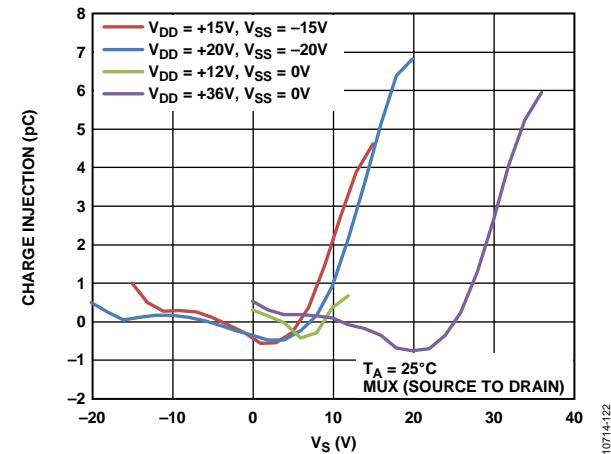
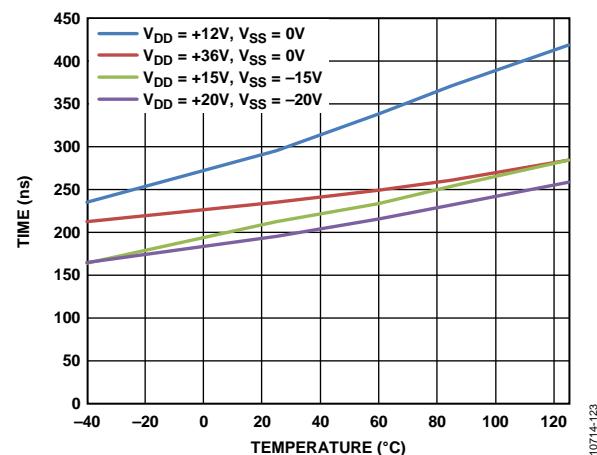
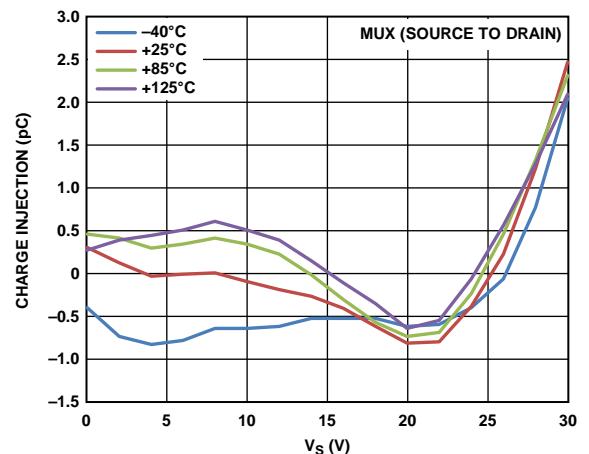
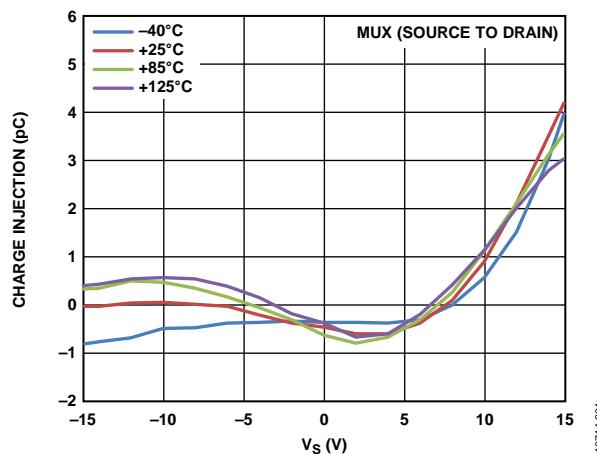
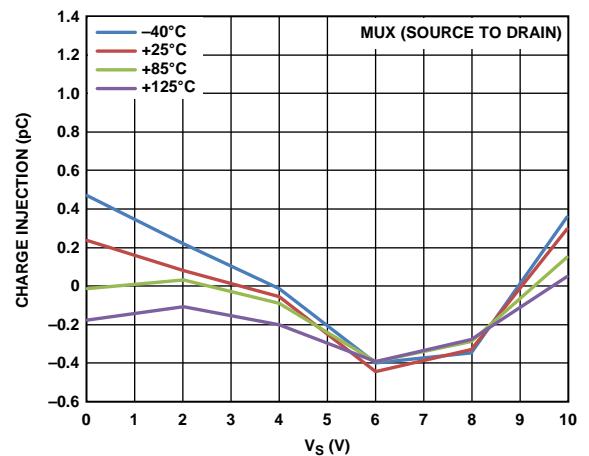
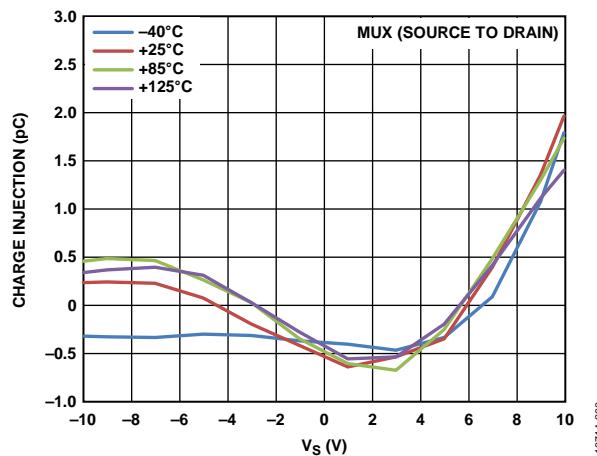


Figure 22. Charge Injection vs. Source Voltage, Source to Drain



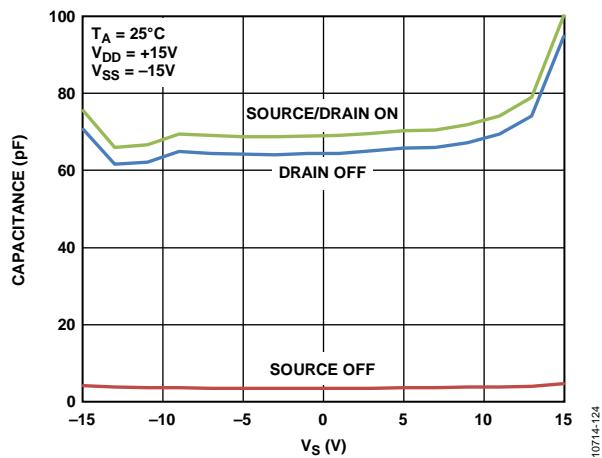


Figure 28. ADG5206 Capacitance vs. Source Voltage,  $\pm 15$  V Dual Supply

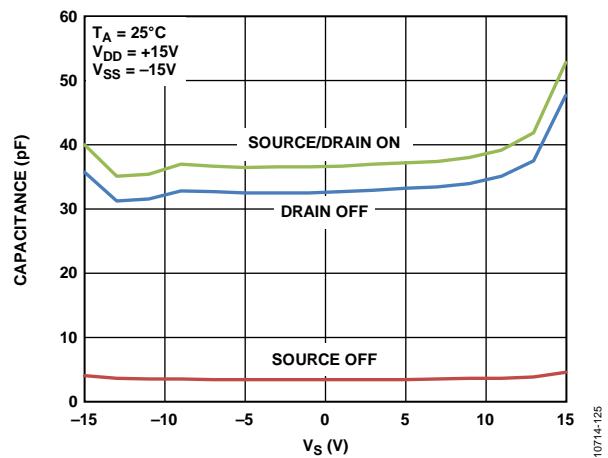
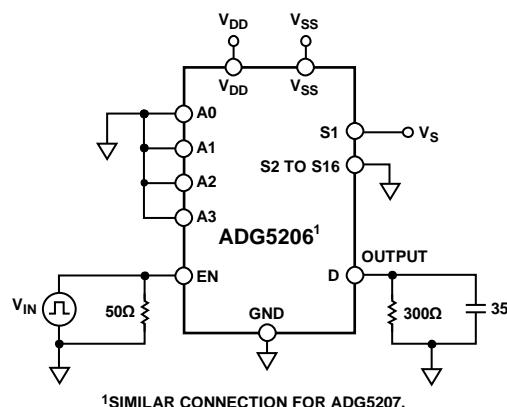
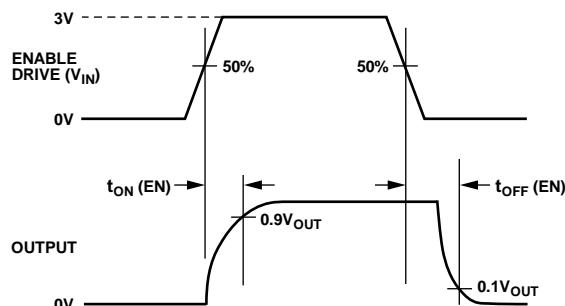
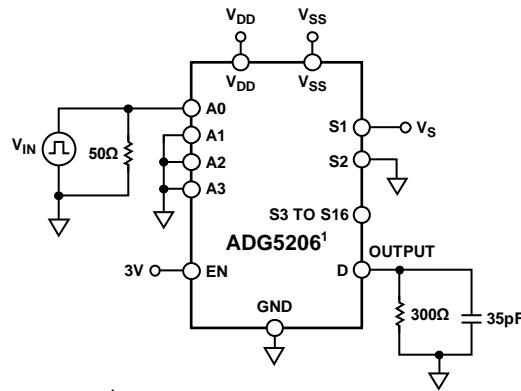
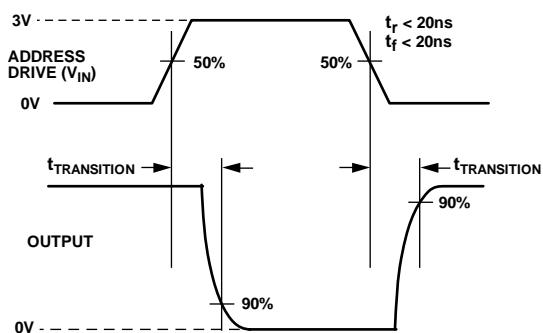
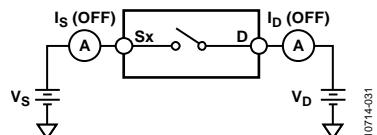
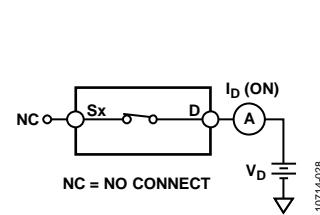
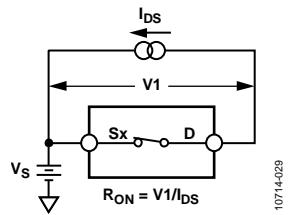
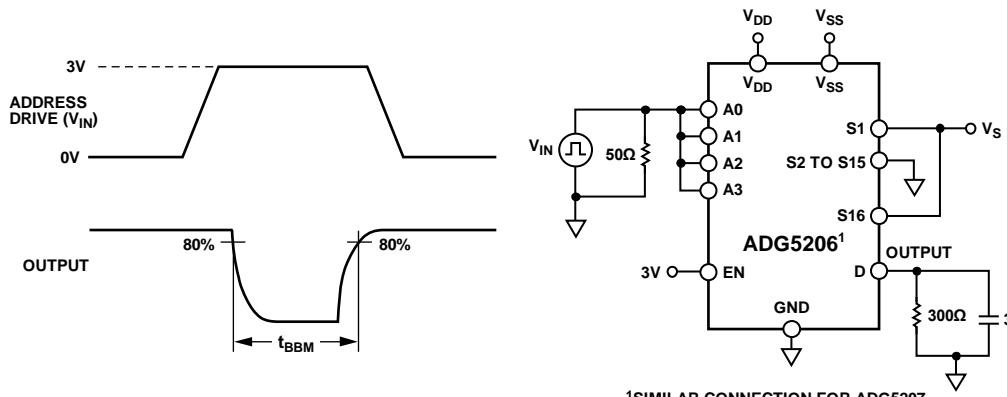


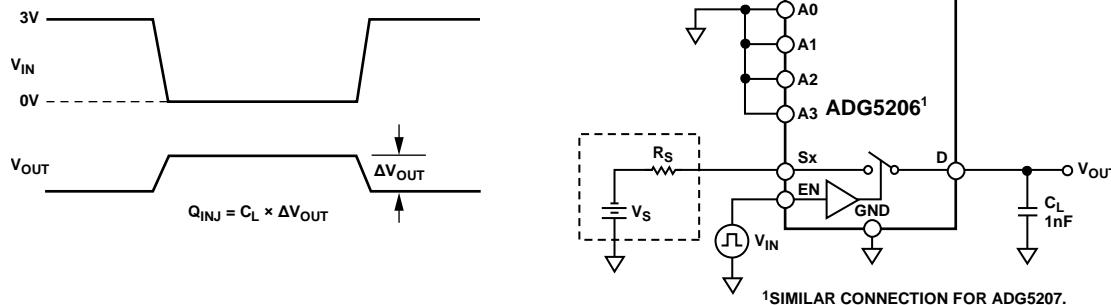
Figure 29. ADG5207 Capacitance vs. Source Voltage,  $\pm 15$  V Dual Supply

## TEST CIRCUITS



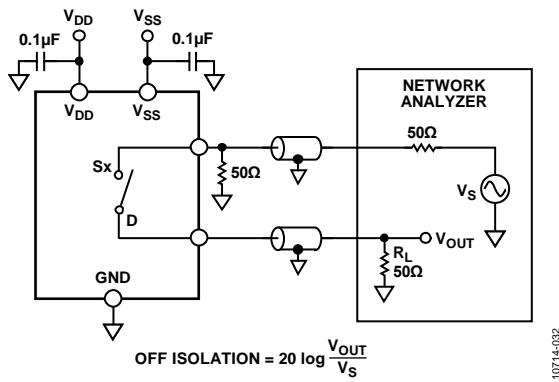
Figure 35. Break-Before-Make Time Delay,  $t_D$ 

10714-035



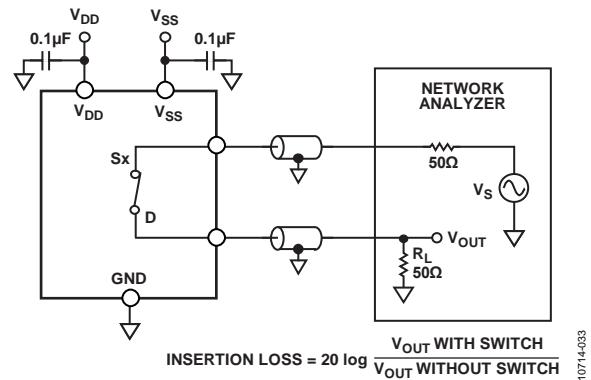
10714-037

Figure 36. Charge Injection



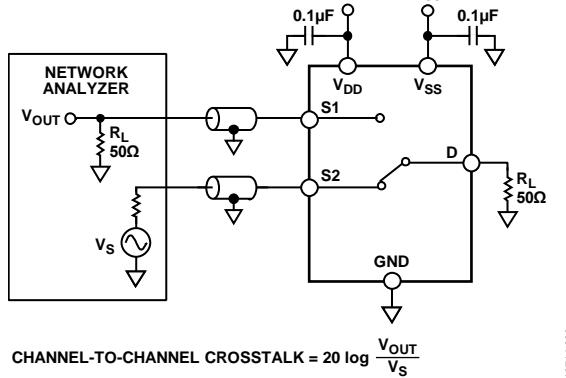
10714-032

Figure 37. Off Isolation



10714-033

Figure 39. Bandwidth



10714-030

Figure 38. Channel-to-Channel Crosstalk

## TERMINOLOGY

**I<sub>DD</sub>**

I<sub>DD</sub> represents the positive supply current.

**I<sub>SS</sub>**

I<sub>SS</sub> represents the negative supply current.

**V<sub>D</sub>, V<sub>S</sub>**

V<sub>D</sub> and V<sub>S</sub> represent the analog voltage on Terminal D and Terminal S, respectively.

**R<sub>ON</sub>**

R<sub>ON</sub> is the ohmic resistance between Terminal D and Terminal S.

**ΔR<sub>ON</sub>**

ΔR<sub>ON</sub> represents the difference between the R<sub>ON</sub> of any two channels.

**R<sub>FLAT (ON)</sub>**

R<sub>FLAT (ON)</sub> is the flatness defined as the difference between the maximum and the minimum value of on resistance measured over the specified analog signal range.

**I<sub>s</sub> (Off)**

I<sub>s</sub> (Off) is the source leakage current with the switch off.

**I<sub>D</sub> (Off)**

I<sub>D</sub> (Off) is the drain leakage current with the switch off.

**I<sub>D</sub> (On), I<sub>s</sub> (On)**

I<sub>D</sub> (On) and I<sub>s</sub> (On) represent the channel leakage currents with the switch on.

**V<sub>INL</sub>**

V<sub>INL</sub> is the maximum input voltage for Logic 0.

**V<sub>INH</sub>**

V<sub>INH</sub> is the minimum input voltage for Logic 1.

**I<sub>INL</sub>, I<sub>INH</sub>**

I<sub>INL</sub> and I<sub>INH</sub> represent the low and high input currents of the digital inputs.

**C<sub>D</sub> (Off)**

C<sub>D</sub> (Off) represents the off switch drain capacitance, which is measured with reference to ground.

**C<sub>s</sub> (Off)**

C<sub>s</sub> (Off) represents the off switch source capacitance, which is measured with reference to ground.

**C<sub>D</sub> (On), C<sub>s</sub> (On)**

C<sub>D</sub> (On) and C<sub>s</sub> (On) represent on switch capacitances, which are measured with reference to ground.

**C<sub>IN</sub>**

C<sub>IN</sub> represents digital input capacitance.

**t<sub>ON</sub> (EN)**

t<sub>ON</sub> (EN) represents the delay time between the 50% and 90% points of the digital input and switch on condition.

**t<sub>OFF</sub> (EN)**

t<sub>OFF</sub> (EN) represents the delay time between the 50% and 90% points of the digital input and switch off condition.

**t<sub>TRANSITION</sub>**

t<sub>TRANSITION</sub> represents the delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

**Break-Before-Make Time Delay (t<sub>D</sub>)**

t<sub>D</sub> represents the off time measured between the 80% point of both switches when switching from one address state to another.

**Off Isolation**

Off isolation is a measure of unwanted signal coupling through an off channel.

**Charge Injection**

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

**Crosstalk**

Crosstalk is a measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

**Bandwidth**

Bandwidth is the frequency at which the output is attenuated by 3 dB.

**On Response**

On response is the frequency response of the on switch.

**AC Power Supply Rejection Ratio (ACPSRR)**

ACPSRR is a measure of the ability of a device to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p. The ratio of the amplitude of signal on the output to the amplitude of the modulation is the ACPSRR.

## APPLICATIONS INFORMATION

The ADG52xx family of switches and multiplexers provides a robust solution for instrumentation, industrial, automotive, aerospace, and other harsh environments that are prone to latch-up, which is an undesirable high current state that can lead to device failure and persist until the power supply is turned off. The [ADG5206/ADG5207](#) high voltage switches allow single-supply operation from 9 V to 40 V and dual-supply operation from  $\pm 9$  V to  $\pm 22$  V.

### TRENCH ISOLATION

In the [ADG5206/ADG5207](#), an insulating oxide layer (trench) is placed between the NMOS and the PMOS transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction isolated switches, are eliminated, and the result is a completely latch-up proof switch.

In junction isolation, the N and P wells of the PMOS and NMOS transistors form a diode that is reverse-biased under normal operation. However, during overvoltage conditions, this diode can become forward-biased. A silicon controlled rectifier (SCR) type circuit is formed by the two transistors, causing a significant amplification of the current that, in turn, leads to latch-up. With trench isolation, this diode is removed and the result is a latch-up proof switch.

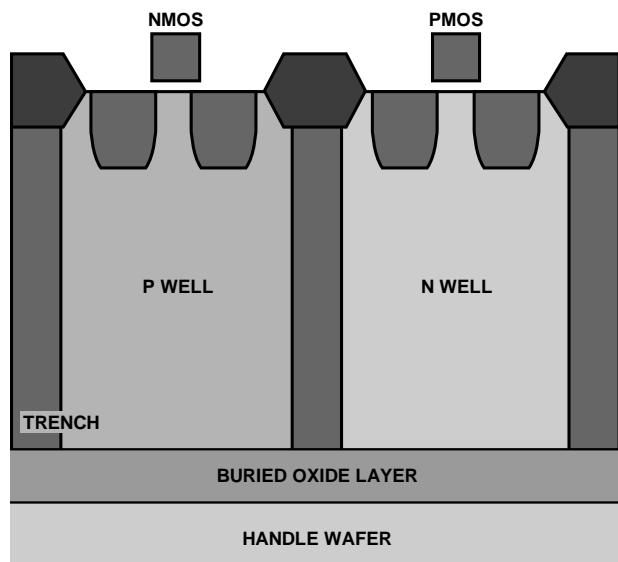
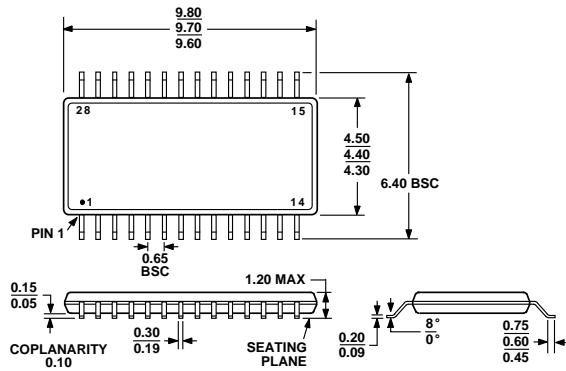


Figure 40. Trench Isolation

10714-038

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AE

Figure 41. 28-Lead Thin Shrink Small Outline Package [TSSOP]  
(RU-28)

Dimensions shown in millimeters

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Package Description	Package Option
ADG5206BRUZ	-40°C to +125°C	28-Lead Thin Shrink Small Outline Package [TSSOP]	RU-28
ADG5206BRUZ-RL7	-40°C to +125°C	28-Lead Thin Shrink Small Outline Package [TSSOP]	RU-28
ADG5207BRUZ	-40°C to +125°C	28-Lead Thin Shrink Small Outline Package [TSSOP]	RU-28
ADG5207BRUZ-RL7	-40°C to +125°C	28-Lead Thin Shrink Small Outline Package [TSSOP]	RU-28

<sup>1</sup> Z = RoHS Compliant Part.